

INCHANGE SEMICONDUCTOR

isc N-Channel MOSFET Transistor

5N65

FEATURES

- Drain Current $I_D=5A@T_C=25$ °C
- Drain Source Voltage
 : V_{DSS}= 650V(Min)
- Static Drain-Source On-Resistance : RDS(on) = 2.4 Ω (Max) @VGS = 10 V
- Avalanche Energy Specified
- Fast Switching
- Simple Drive Requirements
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

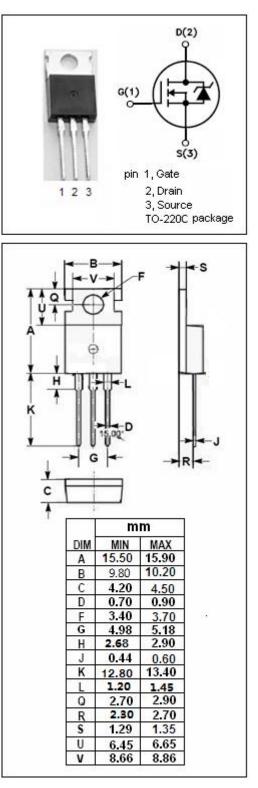
• Designed for high efficiency switch mode power supply.

• ABSOLUTE MAXIMUM RATINGS(Ta=25 C)							
SYMBOL	PARAMETER	VALUE	UNIT				
V _{DSS}	Drain-Source Voltage	650	V				
V _{GS}	Gate-Source Voltage-Continuous	±20	V				
ID	Drain Current-Continuous	5	A				
I _{DM}	Drain Current-Single Plused		А				
PD	Total Dissipation @T _c =25℃	100					
Tj	Max. Operating Junction Temperature	150	°C				
T _{stg}	Storage Temperature	-55~150	°C				

• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	МАХ	UNIT
R _{th j-c}	Thermal Resistance, Junction to Case	1.2	°C/W
R _{th j-a}	Thermal Resistance, Junction to Ambient	62.5	°C/W



isc website: <u>www.iscsemi.com</u>

¹ *isc & iscsemi* is registered trademark



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• ELECTRICAL CHARACTERISTICS

 $T_{\text{C}}\text{=}25^\circ\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	МАХ	UNIT
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0; I _D = 0.25mA	650		V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} = V _{GS} ; I _D = 0.25mA	2	4	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D = 2.5A		2.4	Ω
I _{GSS}	Gate-Body Leakage Current	V _{GS} = ±30V; V _{DS} = 0		±100	nA
loss	Zero Gate Voltage Drain Current	V _{DS} = 650V; V _{GS} = 0		1	μA
V _{SD}	Forward On-Voltage	I _S = 5A; V _{GS} = 0		1.4	V

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